

Freeform Search

Database:	US Pre-Grant Publication Full-Text Database
	US Patents Full-Text Database
	US OCR Full-Text Database
	EPO Abstracts Database
	JPO Abstracts Database
	Derwent World Patents Index
	IBM Technical Disclosure Bulletins

Term:	L9 and 17
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Display:	<input type="text" value="50"/> Documents in Display Format: <input type="text" value="-"/> Starting with Number <input type="text" value="1"/>
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Generate: ☐ Hit List ☒ Hit Count ☐ Side by Side ☐ Image

Search

Clear

Interrupt

Search History

DATE: Friday, September 10, 2004 [Printable Copy](#) [Create Case](#)

<u>Set</u> <u>Name</u>	<u>Query</u>	<u>Hit</u> <u>Count</u>	<u>Set</u> <u>Name</u> result set
side by side			
<i>DB=PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=OR</i>			
<u>L11</u>	L9 and 17	41	<u>L11</u>
<u>L10</u>	L9 and 17	41	<u>L10</u>
<u>L9</u>	l1 and threshold\$3 and voltag\$1 and (mos with transistor\$1) and modulat\$3 and (resistor\$1 or resistance or resistive)	998	<u>L9</u>
<u>L8</u>	L7 and 16	0	<u>L8</u>
<u>L7</u>	326/\$.ccls.	21989	<u>L7</u>
<u>L6</u>	L5 and modulat\$3	68	<u>L6</u>
<u>L5</u>	L4 and resistor\$1	438	<u>L5</u>
<u>L4</u>	L2 and (mos with transistor\$1)	646	<u>L4</u>
<u>L3</u>	L2 and (mos with transistor\$1)	1	<u>L3</u>
<u>L2</u>	L1 with threshold\$3 with voltag\$1	2534	<u>L2</u>
<u>L1</u>	current adj sourc\$3	159339	<u>L1</u>

END OF SEARCH HISTORY